Unit in mm

TOSHIBA PHOTO DIODE SILICON PIN

TPS703, TPS704

SILICON PIN PHOTO DIODE FOR REMOTE CONTROL

VARIOUS KINDS OF REMOTE CONTROL SYSTEMS

SMOKE SENSOR

OPTICAL COMMUNICATION

Detector for visible, fluorescent, and other disturbance light.

TPS703 : $\lambda > 700$ nm TPS704: $\lambda > 800$ nm

High sensitivity $TPS703 : ISC = 1.5 \mu A (Typ.)$

 $TPS704 : I_{SC} = 0.9 \mu A (Typ.)$

High speed response : tr, tf=100ns (Typ.)

Wide half value angle : $\theta = \pm 65^{\circ}$ (Typ.)

TLN105B, TLN115A, etc. are available as high radiant power

infrared LEDs.

SENSITIVE CENTER (0.9) 13 $2 - \Box 0.5 \pm 0.1$

 7.0 ± 0.2

(5.08)LIGHT RECEIVING SURFACE CATHODE INDEX

(): REFERENCE VALUE

` '		
JEDEC	_	
EIAJ	_	
TOSHIBA	0-7B1	

(C MARK)

Weight: 0.31g (Typ.)

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Reverse Voltage		$v_{ m R}$	20	V	
Power Dissipation		$P_{\mathbf{D}}$	150	mW	
Power Dissipation	TPS703	ΔP _D /°C	-2.36	mW/°C	
Derating (Ta>25°C)	TPS704	21 D/ C	-4.3		
Operating Temperature	TPS703	${ m T_{opr}}$	-30~80	°C	
Range	TPS704	ropr	-30~60		
Storage Temperature	TPS703	$ m T_{stg}$	-40~90	°C	
Range	TPS704	1 stg	-40~60		
Soldering Temperature · Time		T_{sol}	260°C⋅3s	_	

PIN CONNECTION



- 1. ANODE
- 2. CATHODE

PRODUCT INDICATION

MONTHLY PRODUCTION LOT

PRODUCTION MONTH (JAN.-DEC. ARE INDICATED BY ALPHABETES OF A-L)

PRODUCTION YEAR (LAST DIGIT OF A.D. IS INDICATED)

MODEL NAME

TPS703:703 TPS704:704

STAMP COLOR: SILVER

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OPTO-ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTE	RISTIC	SYMBOL	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
Short Circuit Current		ISC	$E=0.1 \text{mW} / \text{cm}^2 \text{ (Note)}$	TPS703	0.9	1.5	_	μ A
				TPS704	0.5	0.9	—	
Dark Current		I_{D}	$V_R = 10V, E = 0$		_	1	30	nA
Open Circuit Vol	tage	v_{OP}	$E = 0.1 \text{mW} / \text{cm}^2 \text{(Note)}$ TPS703		150	250	_	mV
Capacitance		$\mathbf{c_T}$	$V_R=3V, f=1MHz$		_	20	<u> </u>	pF
Peak Sensitivity Wavelength		$\lambda_{\mathbf{P}}$	_	TPS703	_	960	-	
				TPS704	_	1000	_	nm
Switching Time	Rise Time	$t_{\mathbf{r}}$	V_R =10V, R_L =1k Ω		_	100	-	***
	Fall Time	t_f		K-104, 14T-1872	_	100	l —	ns
Half Value Angle	Half Value Angle $\theta_{\frac{1}{2}}$		_	±65	<u> </u>	۰		

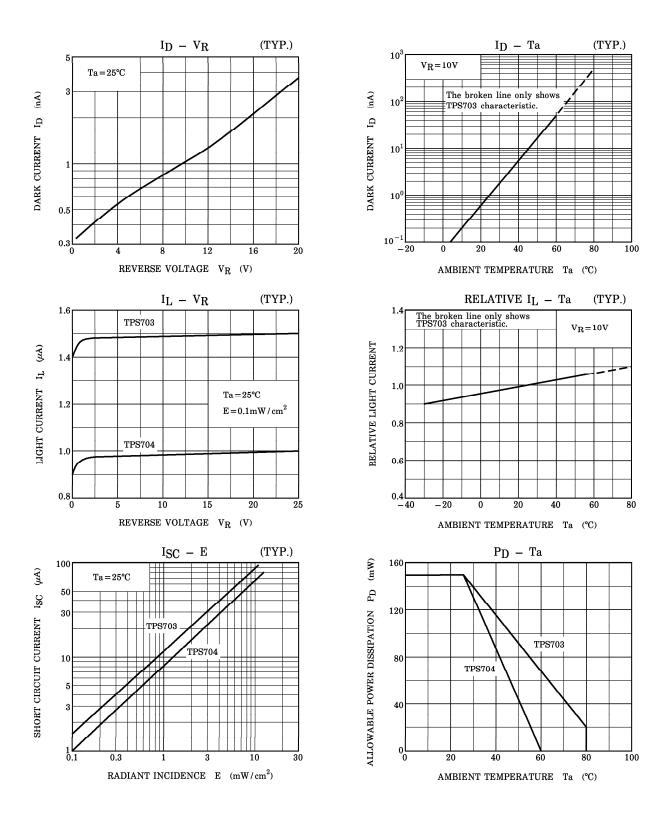
Note: Color temperature=2870°K, Standard Tungsten Lamp.

PRECAUTION

Please be careful of the followings.

- 1. Soldering shall be performed at a portion of lead above 2.3mm from the body of the device.
- 2. If the lead is formed, the lead should be formed at a distance of 2.3mm from the body of the device.

Soldering shall be performed after lead forming.



DIRECTIONAL SENSITIVITY CHARACTERISTIC (TYP.) (Ta = 25°C)

